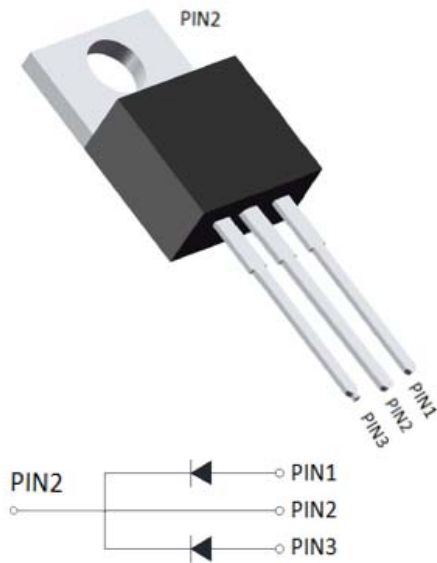


Ultra-Fast Recovery Rectifier Diodes



Features

- High frequency operation
- High surge forward current capability
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Adopt GPP chip
- Passivation for enhanced ruggedness and long term reliability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

Mechanical Data

- **Package:** TO-220AB
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked

■ Limiting Values (Absolute Maximum Rating)

PARAMETER	SYMBOL	UNIT	SF1620CT-B1-0000S
Device Marking Code			SF1620CT
Repetitive Peak Reverse Voltage	VRRM	V	200
Average Rectified Output Current @60Hz half sine-wave, R-load, Tc(FIG.1)	Io	A	16
Surge(Non-repetitive)Forward Current @60Hz half sine- wave, 1 cycle, Ta=25°C	IFSM	A	100
Current Squared Time @1ms≤t<8.3ms Tj=25°C, Rating of per diode	I ² t	A ² s	41
Storage Temperature	Tstg	°C	-55 ~ +150
Junction Temperature	Tj	°C	-55 ~ +150

■ Electrical Characteristics (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	SF1620CT-B1-0000S
Maximum instantaneous forward voltage drop per diode	VFM	V	IFM=8.0A	0.975
Maximum DC reverse current at rated DC blocking voltage per diode	I _{RRM1}	uA	VRM=VRRM Ta=25°C	10
	I _{RRM2}		VRM=VRRM Ta=125°C	500
Reverse Recovery Time	T _{rr}	ns	IF=0.5A I _{RM} =1A I _{RR} =0.25A	35

■ Thermal Characteristics (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	SF1620CT-B1-0000S
Thermal Resistance Between junction and case	R _{θJ-C}	°C/W	2.0

Ordering Information (Example)

PREFERED P/N	UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
SF1620CT-B1-0000S	Approximate 1.88	50	1000	5000	Tube

Characteristics (Typical)

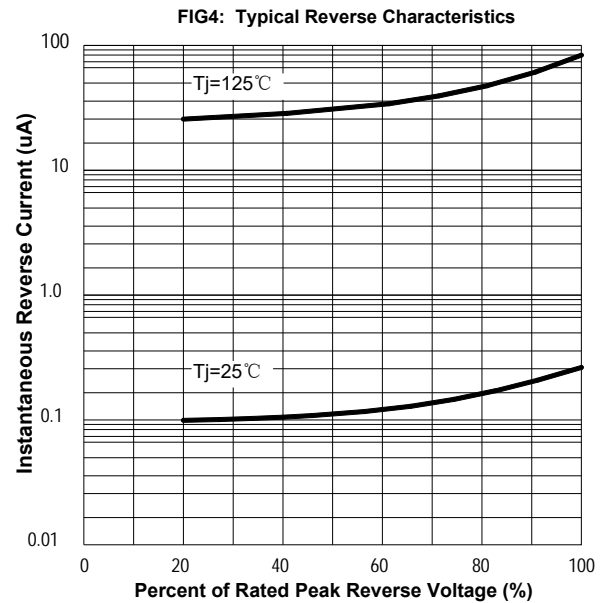
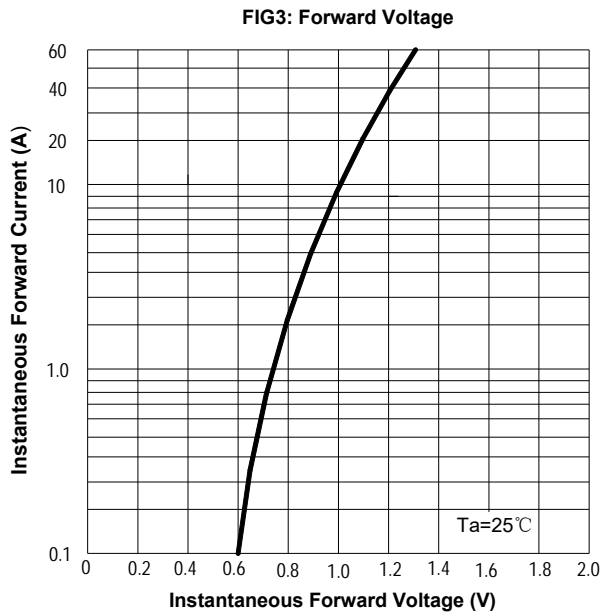
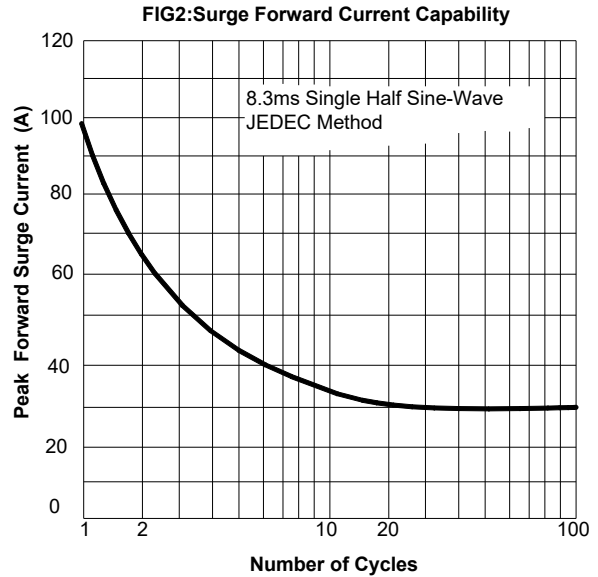
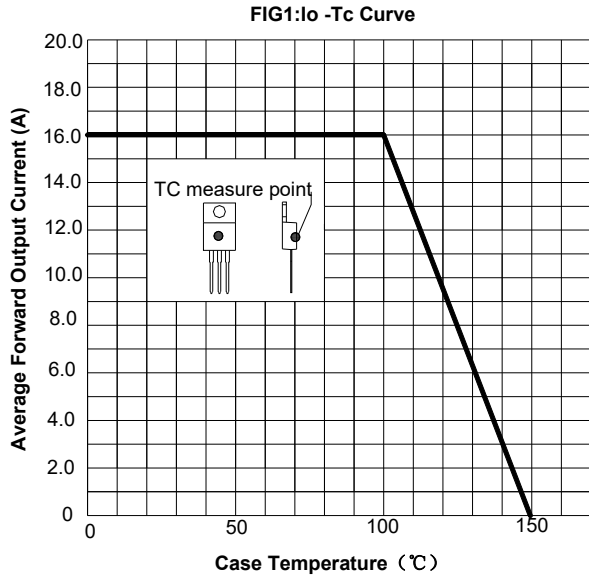
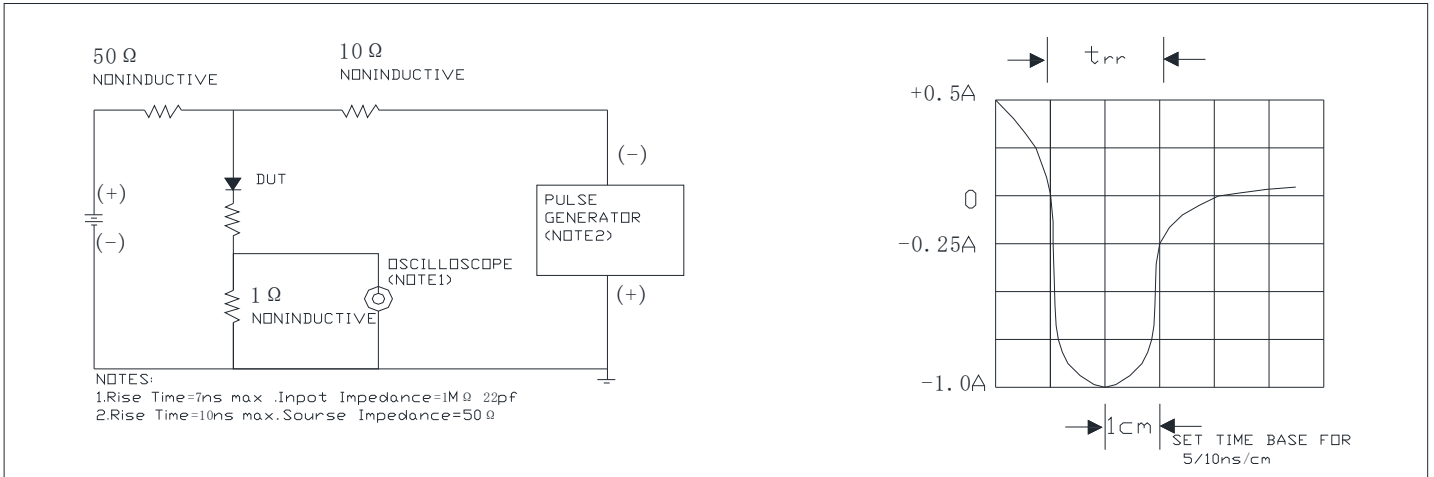
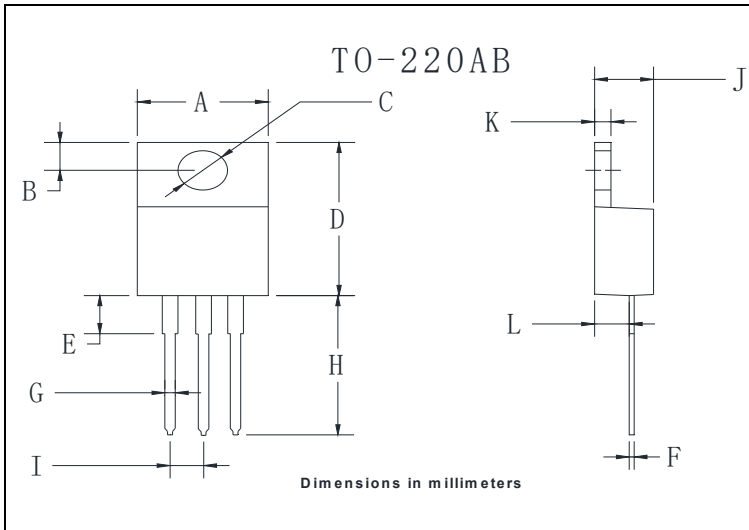


FIG.5 Diagram of circuit and Testing wave form of reverse recovery time



Outline Dimensions



TO-220AB		
Dim	Min	Max
A	9.5	10.9
B	2.22	3.27
C	3.34	4.31
D	14.5	15.5
E	3.16	4.46
F	0.28	0.64
G	0.68	0.94
H	13.06	14.62
I	2.01	3.07
J	4.04	5.1
K	1.14	1.4
L	2.14	3.19

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